Orbital Dim erization and Dynamic Jahn-Teller E ect in NaTiSi2O6

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We study with R am an scattering technique two types of phase transitions in the pyroxene compounds N aM $\rm Si_2O_6$ (with M = Ti, V, and Cr). In the quasione-dimensional S= 1/2 system N aT $\rm iSi_2O_6$ we observe anomalous high-tem perature phonon broadening and large changes of the phonon energies and line-widths across the phase transition at 210 K. The phonon anomalies originate from an orbital order-disorder phase transition and these results {combined with theoretical considerations{indicate that the high temperature dynamical Jahn-Teller phase of N aT $\rm iSi_2O_6$ exhibits a spontaneous breaking of translational symmetry into a dimerized, Jahn-Teller distorted, orbital ordered state under the formation of spin valence bonds. In S= 1 N aV $\rm Si_2O_6$ orbital degrees of freedom are strongly suppressed and the magnetic excitations are well described within a Heisenberg model, indicating that at T $\rm N$ = 19K this system orders antiferrom agnetically.

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Introduction. Electrons in strongly correlated transition-metal compounds can be regarded as having separate spin, charge and orbital degrees of freedom. It is the interplay between these, combined with their coupling to the lattice, that gives rise to a wealth of possible spin, charge and orbital orderings, as observed for instance in many ColossalM agneto-Resistance manganites [1], cuprates [2], titanates (e.g. LaT iO $_3$ [3]) and vanadates (e.g. V $_2$ O $_3$ [4] and LiVO $_2$ [5]).

System swith orbital degeneracy are particularly interesting because orbitals couple to the lattice via the cooperative Jahn-Teller (JT) e ect on one hand, and via superexchange interactions to the electronic spin on the other hand [2]. Therefore at an orbital ordering phase transition the magnetic susceptibility and phonon properties will be a ected at the same time. Experimentally, however, such an interrelation is seldom found: in general the dominant JT orbital-lattice coupling obscures the more subtle e ects due to the superexchange.

Pyroxenes are large family of compounds (AMB₂O₆; A=alkalim etal, M=transition-metal, and B=Si, Ge) which structure consists of isolated quasi one-dimensional chains of edge-sharing MO₆ octahedra, linked together by the comer-sharing BO₄ tetrahedra, Fig. 1. Particularly, the compounds with active t_{2g} orbitals (M=Ti,V, and Cr) are expected to have electronic interactions governed by both orbital degeneracy and anisotropy. Interestingly, the sodium-silicon system with titanium, NaTiSi₂O₆, is rather dierent from other pyroxenes as it lacks low-tem perature AF order, and shows signs of the opening of a spin gap instead [6, 7, 8, 15]. Ti³⁺ corresponds to S=1/2, and since all Ti ions are in equivalent crystallographic positions, this material is a prime candidate to show a spin-Peierls (SP) phase transition. Indeed, its magnetic susceptibility [6] sharply decreases below 210 K, indicating a transition to a spin-singlet state, which could in principle be of the SP type. But already the high-tem perature magnetic susceptibility data does not support such a SP scenario, since the phase transition occurs at a tem perature that is higher then the maximum point of the Bonner-Fisher curve, which implies that the transition cannot solely be driven by magnetic uctuations [6]. Based on structural analysis, Isobe et al. anticipated that orbital dimerization might be responsible for such behavior [6].

In this Letter, we report a Ram an scattering study on a family of pyroxene compounds from which we conclude that orbital degrees of freedom play decisive role in physical properties of NaTiSi $_2$ O $_6$, and that NaTiSi $_2$ O $_6$ undergoes an orbital order phase transition at ToO = 210 K. At high temperatures the uctuations of the orbital degrees of freedom lead to a dynamic Jahn-Teller phase with anomalous phonon broadening and remant antiferrom agnetic (AF) spin uctuations. We not that the dramatic drop of the magnetic susceptibility below ToO is accompanied with a structural change, just as one would expect for a canonical orbital ordering transition. These results, combined with the microscopic orbital-spin model that we derive, suggest that the quasione-dimensional dynamical Jahn-Teller phase of NaTiSi $_2$ O $_6$ exhibits a spontaneous breaking of the translational symmetry into an dimerized orbital ordered state with a spin gap due to the formation of spin valence bonds. The paper is organized as follows: rst we present the Raman spectra and underline in portant observations, then we discuss the electronic structure of pyroxenes and derive a microscopic model. Finally, we demonstrate that all observed e ects (including susceptibility data) can be

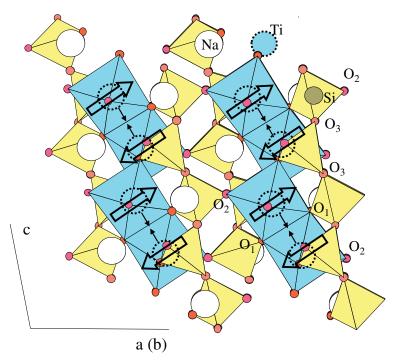


FIG. 1: a) C rystal structure of N aT iS i_2 O i_3 . B lock arrows denote m agnetic m om ents, and sm all arrows represent possible distortions (dim erization) of the T iO i_3 octahedra in the low temperature phase.

accounted by our model.

Experim ent.H igh-quality powder samples of NaM $\rm Si_2O_6$ (M = Ti, V, and Cr) were prepared by a solid-state reaction of mixtures with an appropriate molar ratio of Na₂M $\rm Si_4O_{11}$, M and MO₂. Details of the sample preparation are published elsewhere [6]. Ram an spectra are measured in the backscattering conguration, using 514.5 nm line of an Ar-ion laser, micro-Ram an system with a DILOR triple monochromator, and a liquid nitrogen cooled charge-coupled device detector. For the low-temperature measurements we used the Oxford continuous-ow cryostat with a 0.5 mm thick window. The focusing of the laser beam is realized with a long distance (10 mm focal length) microscope objective (magnication 50).

The pyroxenes crystallize in a monoclinic unit cell with the space group C 2=c [9]. The unit cell consists of four formula units (Z=4) with 40 atoms in all. The site symmetry of Na, M, Si, O₁, O₂ and O₃ atoms are (4e), (4e), (8f), (8f), (8f) and (8f), respectively. Thus, the factor-group-analysis (FGA) yields: (Na, M) (C₂) = A_g + A_u + 2B_{1g} + 2B_u; (Si, O₁, O₂, O₃) (C₁) = 3A_g + 3A_u + 3B_g + 3B_u. Summarizing these representations and subtracting the acoustic modes (A_u + 2B_u), we obtain the following irreducible representations of NaM Si₂O₆ vibrational modes:

opt:

$$_{N \text{ aM S } i_2 \circ \circ}$$
 = 14A $_{g}$ (xx;yy;zz;xz) + 16B $_{g}$ (xy;yz)
+ 13A $_{u}$ (E jjy) + 14B $_{u}$ (E jjx;E jjz)

The unpolarized R am an spectra of N aM $\rm Si_2O_6$ (M = Ti, V , Cr) are shown in Fig. 2. At the room temperature we nd around 30 phonon modes as predicted by FGA. The R am an spectra of di erent compounds are similar as expected for isostructural materials, and the phonon modes can be crudely grouped into two energy regions. The modes in the spectral range below 500 cm 1 originate from the bond bending vibrations, whereas the higher frequency modes originate from the stretching vibrations. The highest energy modes are mainly due to the non-bridging Si-O ion vibrations, because of the shortest Si-O tetrahedral bonds. The modes of N aM Si2O 6 at 1055/1032 cm 1 (Cr), 1042/1025 cm 1 (V), and 1042/1025 cm 1 (Ti), represent Si-O 2 (see Fig. 2) antisymmetric/symmetric bond stretching vibrations, respectively. Their frequency di erence scales as R 3 in a full accordance with dierence between Si-O 2 bond lengths in these materials. Similarly, the modes at 990/967 cm 1 (Cr), 972/954 cm 1 (V), and 965 cm 1 (Ti), we assign as antisymmetric/symmetric pairs of Si-O 1 bond stretching modes. This simplified mode assignment becomes inapplicable at lower frequencies due to more complicated normal coordinates of corresponding vibrations. However, besides similarities, we also observe two very important elects. First, most of the phonon line widths are dramatically increasing in the components with smaller spin values (V $^{3+}$! S = 1; C $^{3+}$! S = 3=2). Second, the spectra of N aT iSi₂O 6, due to the large phonon broadening, show electively less phonon modes then expected by FGA, and observed in other pyroxenes. The latter elect may also be regarded as a consequence of a high temperature "higher

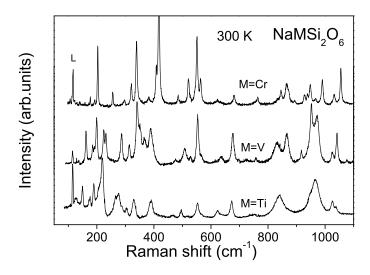


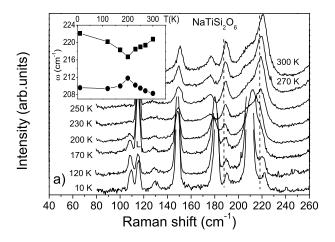
FIG. 2: Ram an spectra of NaM SigO 6.

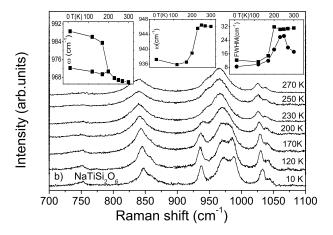
sym m etry lattice state" of NaTiSi2O6.

By lowering the tem perature we ind a dram atic change in the phonon R am an spectra of NaT iSi $_2$ O $_6$ around 210 K, see Fig. 3a,b. The modes at 221 and 209 cm $^{-1}$ exhibit the anti-crossing behavior, see inset Fig.3a, which indicates that these two modes belong to the same symmetry class below T_c . A similar elect is observed for all other such pair of modes (one more pair is also visible in Fig. 3a at about 180 and 190 cm $^{-1}$) in the spectra, which suggests that in the low-T phase of NaT iSi $_2$ O $_6$ all R am an active modes are of the same (A $_g$) symmetry type. Furthermore, our rejectance measurements (will be published separately, Ref. [10]) show that the infrared active phonon modes can be distinguished from the R am an modes, since the center of inversion remains to be the symmetry element in the low-T phase. Accordingly, we uniquely determine the space group of the low-T phase of NaT iSi $_2$ O $_6$ to be P $_2$ T. This space group requires the translation symmetry breaking of the TiO $_6$ chain (the tentative distortion pattern of the low-T phase is shown in Fig. 1) which is in agreement with preliminary X-ray different and neutron scattering data [11].

M oreover, we show in details the tem perature dependence of the structure around 970 cm 1 , Fig. 3b. The mode at about 946 cm 1 softens by about 10 cm 1 , while mode at 966 cm 1 "splits", and hardens by 25 cm 1 , see inset in Fig. 3b. The full width at half maximum (FW HM) of the 946 cm 1 (circles) and 966 cm 1 (squares) phonons (the FW HM is estimated from Lorenzian-t) increase up to the maximum value at about 210 K, and then decreases to the saturation value which is much smaller then the T=300 K value, see right inset of Fig. 3b. In fact, all R am an-active phonons exhibit anomalies at the temperature which coincides with T_c obtained from susceptibility measurements [6] indicating that the magnetic ordering is accompanied with the structural phase transition just as one would expect for an canonical orbital-ordering transition. Besides, behavior of FW HM implies that the bond uctuations are considerably larger in the high-T then in low-T phase (proximity of the structural phase transition induces the largest uctuations, producing the maximum FW HM at T_{00}). Due to the JT elect bond uctuations emphasize the strong orbital character of disorder above the phase transition temperature [12, 13].

Contrary to S=1/2 compound, in the low temperature Raman spectra of NaVSi2O6, see Fig. 3c, we did not observe the phonon anom alies. Instead, at low tem peratures, broad asymm etric features, typical for the two-magnon $_{i;j}\,J_{i;j}S_{i}$ §; $J_{i;j}>$ 0), appear around 260 and 400 cm 1 . A coording to the excitations in Heisenberg AF (H = linear Anderson's approximation, dierential cross section for the two-magnon (tm) Raman scattering is proportional $_{\boldsymbol{k}}$ (! 2! (k)). The dispersion relation is obtained assum inq to the two-magnon density of states (DOS), I_{tm} two-dim ensionalm agnetic structure w ith dierent exchange interactions along the chains (J_k) , and perpendicular (J_2) $(J_k \cos (ka) + J_2 \cos (kb))^2$. The calculated two-magnon DOS is shown in top to the chains: !(k) = 2S' $(J_k + J_?)^2$ panel of Fig. 3c. Two singularities at energies of about 260 and 390 cm⁻¹ are obtained for $J_k = 85$ cm⁻¹ and $J_2 = 13$ $\,$ cm 1 (120 K and 18 K, respectively), in a very good agreement with experiment. The maximum of the susceptibility curve in NaVSi₂O₆ is at about 100 K [11] (giving J_k 80 K [14]) which is in good agreem ent with our estimation of the J_k . Thus, we conclude that NaVSi₂O₆ exhibits an AF ordering. Sim ilar AF phase has been already observed in other S=1 chain compounds LiVG e_2O_6 [7], and NaVG e_2O_6 [15].





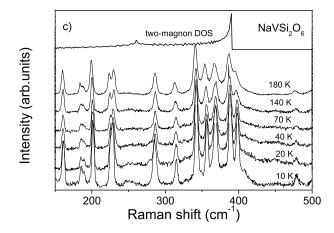


FIG. 3: Temperature dependence of the Ram an spectra in a),b) NaTiSi $_2$ O $_6$, and c) NaVSi $_2$ O $_6$. Top panel in c) shows calculated two-m agnon density of states. Insets: Temperature dependencies of the frequency and line width of various phonons in NaTiSi $_2$ O $_6$. Vertical dashed line is an guide for the eye.

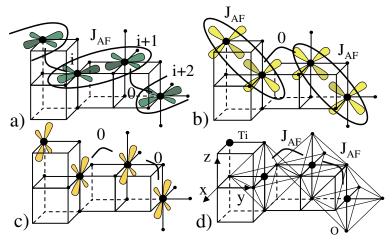


FIG. 4: Schem atic presentation of the orbital ordering in NaTiSi $_2$ O $_6$. Orbital overlap in a) xy, b) yz, and c) xz planes. d) Heisenberg AF phase.

Pyroxenes: theoretical. Next we discuss the electronic structure. For a single octahedron the cubic crystal eld splits the Ti,V or Cr 3d-states into low lying t_{2g} states, with 1,2 or 3 electrons, respectively, and empty states of e_g sym metry at higher energy. The low energy electronic properties are governed by the three-fold degenerate t_{2g} states (the relevant states are jkyi, jyzi and jzxi) [16].

The Coulomb interaction U between electrons on the same transition metal atoms is large, so the exchange interactions can be determined by a second order perturbation expansion in the electron hopping parameters. The problem is further reduced by considering the symmetry allowed hopping paths in the chain geometry, schematically represented in Fig. 4. If we consider orbitals on two sites in the same xy plane, then only the hopping between jxyi orbitals is relevant (see Fig. 4a). For sites in the yz plane, the jyzi orbitals are relevant, Fig. 4b. In the present geometry (note that x, y, and z in Fig. 4 do not correspond to a, b, and c axis in Fig. 1) there are no transition metal atoms in the same chain that are also in the same xz plane. The jxzi orbitals are therefore non-bonding and can be considered inert on this level of approximation (a tightbinding parametrization [17] shows that other overlap integrals either vanish by symmetry or are more than factor ve smaller), see Fig. 4c. For the S= 1/2 Titanium system we then obtain the Ham iltonian [18],

$$H^{Ti} = jJ^{Ti} j X_{i;j} S_{i} S_{j} \left[\frac{1}{4} + T_{i}^{z} T_{j}^{z} + \frac{(1)^{i}}{2} (T_{i}^{z} + T_{j}^{z}) \right];$$
 (1)

where we use the orbital operators T ($T_i^z=1=2$ corresponds to an occupied jxyi orbital and $T_i^z=1=2$ to an occupied jxzi orbital on site i), and i; j are neighboring sites. For the S=1 Vanadium and S=3/2 C hrom ium system the orbital degree of freedom vanishes (T=0) as the both of the active orbitals are occupied, so for the spin system we obtain a simple H eisenberg H am iltonian H $^{V=C\,r}=jJ^{V=C\,r}$ j $_{i,j}$ S_i. This imm ediately explains the uniqueness of the T i (S=1/2) system, and the antiferrom agnetism in NaV Si₂O 6 (in fact in all S \odot 1=2 pyroxenes).

Interpretation of experim ents. The ground state of H am iltonian (1), is clearly a ferro-orbital state, with spin-singlets on each bond, where the energy per dimer is $3J^{T}=4$. The state with all jxyi occupied is degenerate with the state with all jxzi occupied, see F ig. 4. Those states do dier, however, because the dimerization pattern along the chain is shifted by one lattice spacing. At zero temperature the system is condensed in either one of these two dimerized orbital ordered states and the translation symmetry is broken. This explains the structural change at T_c [11], the symmetry change and the energy shifts of the phonon excitations in the R am an spectra of N aT iS $\frac{1}{2}$ O $_6$, and the observation of a large spin gap in the susceptibility measurements [6].

At high tem peratures, due to strong orbital-lattice coupling and JT e ect, the orbital uctuations produce dramatic e ects. Above T_{00} the JT distortion disappears: the high-T orbital disordered phase of NaTiSi $_2$ O 6 m ay be regarded as an orbital uctuating phase, and on larger time scales the TiO 6 octahedra appear to be undistorted. This causes the crystal to be e ectively more symmetric, which is in agreement with the observation of less-then-expected phonon modes in the room temperature Raman spectra. As a consequence, orbital uctuations induce large phonon broadenings (of course, the modes with TiO bonds in their normal coordinates will be mostly a ected), as they are indeed found in the room temperature Raman spectra of NaTiSi $_2$ O 6, see Fig. 2. In that respect the high-T phase of NaTiSi $_2$ O 6 resembles a dynamical JT phase (where the phonon broadening is a signature of the melted static lattice distortions [12, 13]). The spin uctuations above the orbital ordering temperature [6] can be easily understood in a

straightforward mean-eld approximation of Hamiltonian (1), where we can decouple orbitals and spins. If the long range order is absent in the orbital sector, we have for the expectation values $hT_i^zi=0$, and $hT_i^zT_j^zij<1=4$, so that the elective exchange constants (and therefore the uctuations in the spin-sector are still antiferrom agnetic. Thus, the nature of the phase transition in NaTiSi2O 6 can be established: it corresponds to an orbital order-disorder phase transition with appropriate concomitant magnetic and lattice changes.

In the case of two electrons per site (NaVSi₂O₆), the orbital uctuations are strongly suppressed due to inert property of j_{xz} i orbitals, and the corresponding phonon broadenings are much smaller, see Fig. 2. NaCrSi₂O₆ has a fully polarized t_{2g} core, no orbital degrees of freedom, and no anom alous phonon broadenings in the Ram an spectra.

Conclusions. We report a study of the two types of the phase transitions, observed in pyroxene family, by analyzing the Ram an-active phonon and magnon excitations, and their temperature dependence. We not that spin S=1/2 compound, NaTiSi $_2$ O $_6$, exhibits a transition at about 210 K that we assign to be an orbital order-disorder phase transition. It originates from the instability of the high temperature orbital uctuating – dynamical Jahn-Teller phase, towards a dimerized orbital ordered state, which is accompanied by a lattice distortion and by spin valence bond form ation. The spin S=1 system, NaV Si_2 O $_6$, on the contrary, does not show this type of instability and orders as a Neel-type antiferrom agnet below $T_N=19$ K in agreement with our microscopic spin-orbitalm odel for the pyroxenes.

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